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Dkt. 2271/53467-A1



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

eissue Application of: Shunichi SATO

For: METHODS FOR GROWING SEMICONDUCTORS AND DEVICES THEREOF

FROM THE ALLOY SEMICONDUCTOR GAINNAS

Reissue Appl'n No.: 10/603,418 Reissue Appl'n Filed: June 24, 2003

Original Patent No.: 5,904,549 Original Patent Issued: May 18, 1999

I hereby certify that this correspondence is being deposited this date with the U.S. Postal Service with sufficient postage as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 223131450.

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Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

In order to ensure compliance with the applicant's duty of disclosure under 37 C.F.R. §1.56 and §1.97(a)-(d), Applicant hereby submits this Information Disclosure Statement.

This Information Disclosure Statement is filed pursuant to 37 C.F.R. §1.97(c)(2). The fee under 37 C.F.R. §1.17(p) for filing an Information Disclosure Statement pursuant to 37 C.F.R. §1.97(c)(2) is \$180.00 and a check in that amount is enclosed.

It is respectfully requested that the information cited in the annexed Form PTO-1449 be considered by the Examiner in connection with the above-identified patent application, and that such art be made of record in said application. Copies of the cited references are enclosed.

The citation of the listed items is not a representation that they constitute a complete or 05/03/2007 LHONDIH1 00000065 10603418

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exhaustive listing of the relevant art or that these items are prior art. The items listed are submitted in good faith, but are not intended to substitute for the Examiner's search. It is hoped, however, that in addition to apprising the Examiner of the particular items, they will assist in identifying fields of

The filing of this Information Disclosure Statement is not an admission that the information cited herein is, or is considered to be, material to patentability as defined in 37 C.F.R. §1.56(b).

search and in making as full and complete a search as possible.

The Patent Office is hereby authorized to charge any additional fees that are required for consideration of this Information Disclosure Statement, and to credit any overpayment during prosecution of this application, to our Deposit Account No. 03-3125.

Respectfully submitted,

Paul Teng, Reg. No. 40,837

Attorney for Applicant Cooper & Dunham LLP

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